Geant 4

IEEE Nuclear Science Symposium and Medical Imaging Conference Short Course

Simulation Techniques Using Geant4

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http://www.ge.infn.it/geant4/events/nss2008/geant4course.html

This course exploits training material developed by several Geant4
Collaboration members: thanks to all of them!



Electromagnetic Physics

Overview



Electromagnetic packages in Geant4

- Standard
- Low Energy
- Optical
- Muons
- Different modeling approach
- Specialized according to particle type, energy scope

Electromagnetic physics

- electrons and positrons
- \bullet γ , X-ray and optical photons
- muons
- charged hadrons
- ions
- High energy extensions
 - needed for LHC experiments, cosmic ray experiments...
- Low energy extensions
 - fundamental for space and medical applications, dark matter and v experiments, antimatter spectroscopy etc.
- Alternative models for the same process

- Multiple scattering
- energy F Bremsstrahlung
 - loss Ionisation
 - Annihilation
 - Photoelectric effect
 - Compton scattering
 - Rayleigh effect
 - g conversion
 - e+e- pair production
 - Synchrotron radiation
 - Transition radiation
 - Cherenkov
 - Refraction
 - Reflection
 - Absorption
 - Scintillation
 - Fluorescence
 - Auger

All obeying to the same abstract Process interface: transparent to tracking



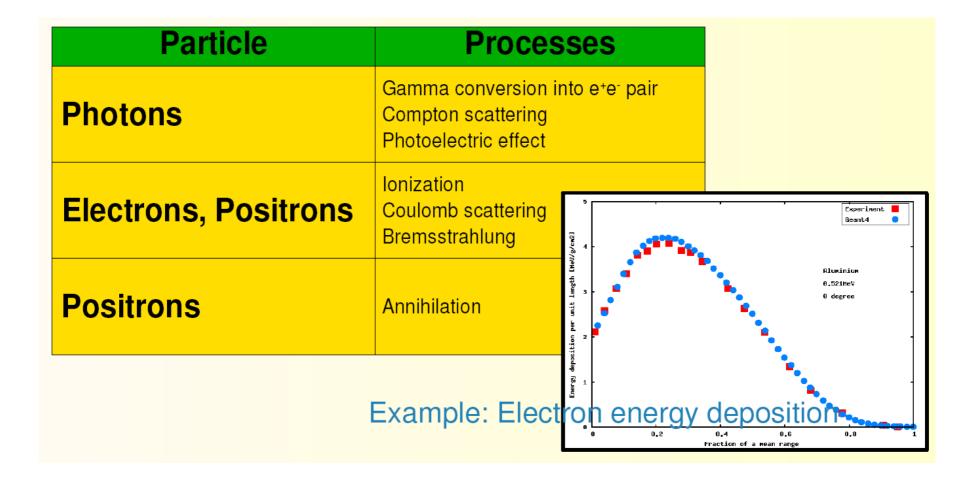
Standard Electromagnetic Physics

Overview

Packages

Package	Description
Standard	Gamma, Electrons up to 100 TeV, Hadrons, lons up to 100 TeV
Muons	Muons up to 1PeV, Energy loss propagator
X-rays	X-ray and optical photon production processes
Optical	Optical photon interactions
High-energy	Processes at high energy (E > 10 GeV), Physics for exotic particles
Polarization	Simulation of polarized beams

Processes: electrons and photons



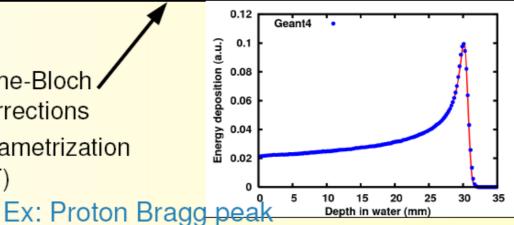
Processes: hadrons

Particle	Processes
Hadrons, lons	Coulomb Scattering, Ionization

$$\frac{dE}{dx} = 2\pi r_e^2 mc^2 n_{el} \frac{z^2}{\beta^2} \left[\ln \left(\frac{2mc^2 \beta^2 \gamma^2 T_{up}}{I^2} \right) - \beta^2 \left(1 + \frac{T_{up}}{T_{max}} \right) - \delta - \frac{2C_e}{Z} + F \right]$$

Ionization:

- E > 2 MeV: Bethe-Bloch formula with corrections
- E < 2 MeV: Parametrization (ICRU 49, NIST)



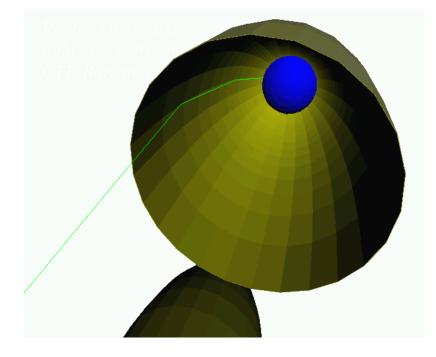
Geant 4

Optical photons

Production of optical photons in detectors is mainly due to Cherenkov effect and scintillation

Processes in Geant4:

- in-flight absorption
- Rayleigh scattering
- medium-boundary interactions (reflection, refraction)



Muons

1 keV up to 1000 PeV scale

- simulation of ultra-high energy and cosmic ray physics
- High energy extensions based on theoretical models

Deviation of 45 GeV muons in L3

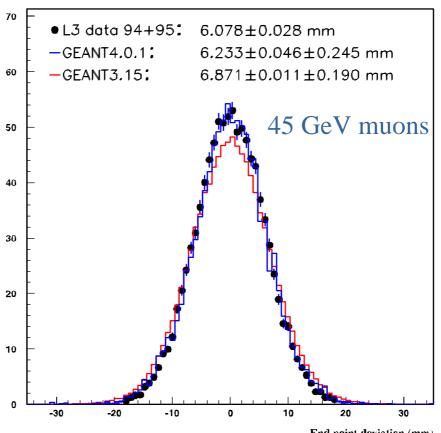
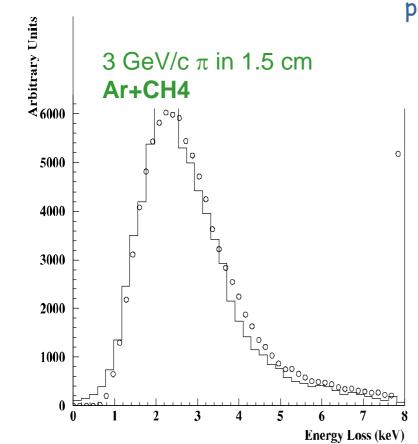
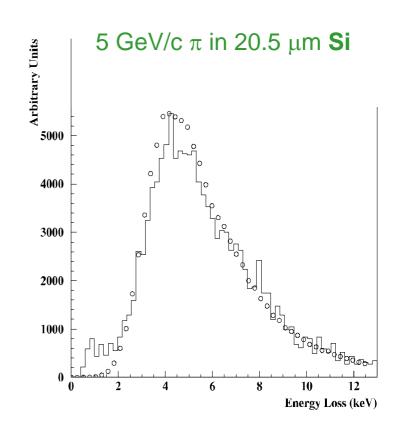


Photo Absorption Ionisation (PAI) Model

Ionisation energy loss produced by charged particles in **thin layers** of absorbers





Ionisation energy loss distribution produced by pions, PAI model



Process ordering

```
void PhysicsEMElectronStandard::ConstructProcess()
    G4ParticleDefinition* electron = G4Electron::Definition();
    G4ProcessManager* manager = electron ->GetProcessManager();
    // Adding multiple Coloumb scattering
    manager -> AddProcess(new G4MultipleScattering(), -1, 1, 1);
    // Adding ionisation
    manager -> AddProcess(new G4eIonisation(), -1, 2, 2);
    // Adding Bremsstrahlung
    manager -> AddProcess(new G4eBremsstrahlung(), -1,-1,3);
```

-1 means that process is not registered for this action

Multiple scattering

- Geant4 is a condensed Monte Carlo code
 - Global effects due to collisions along a macroscopic step are simulated, using approximations
- Is in contrast to detailed simulations at a microscopic level, which are exact, but require an enormous amount of time for higher energies

Cumulative effects

- Charged particles, that travel through a finite material layer are subject to a large number of Coloumb interactions, where the particles are elastically scattered
- Summing up individual effects gives a net deflection of the particles from their initial direction
- For sufficient collisions (>20) multiple scattering angular distribution is
 - a Gaussian distribution for small angles
 - like Rutherford scattering at large angles



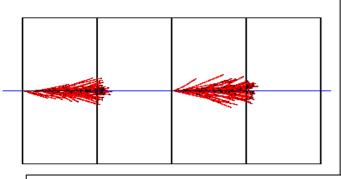
Multiple scattering

- The Geant4 Multiple Scattering (MSC) model by L. Urban is applicable to all charged particles
- It is based on the Lewis theory
- Relies on transport equation of charged particles
- Uses phenomenological functions to sample angular and spatial distributions after the simulation step
 - The function parameters are chosen, in order that the moments of the distribution are the same as given by the Lewis theory
- See the Physics Reference Manual for details

Ionisation

The basic mechanism is an inelastic collision of the moving charged particle with the atomic electrons of the material, ejecting off an electron from the atom :

$$\mu + atom \rightarrow \mu + atom^+ + e^-$$



Mean energy loss and energetic δ -rays

$$\frac{d\sigma(Z, E, T)}{dT}$$

is the differential cross-section per atom for the ejection of an electron with kinetic energy T by an incident charged particle of total energy E moving in a material of density ρ .

One may wish to take into account separately the high-energy knock-on electrons produced above a given threshold T_{cut} (miss detection, explicit simulation ...).

 $T_{cut} \gg I$ (mean excitation energy in the material).

 $T_{cut} > 1 \text{ keV in Geant4}$

Below this threshold, the soft knock-on electrons are counted only as continuous energy lost by the incident particle.

Above it, they are explicitly generated. Those electrons must be excluded from the mean continuous energy loss count.

High energy knock-on electrons

- Above a given threshold Tcut high energy knock-on electrons are explicitly taken into account
 - i.e. δ -rays are explicitly generated (particles excluded from continuous energy loss)
- Below Tcut the soft electrons are only considered as continuous energy loss of the incident particle

Energy loss fluctuations

- Urban model of fluctuations,
 - based on a simple modelling approach of particle-atom interactions:
- Atoms are assumed to have only two energy levels:
 E1 and E2
- The particle-atom interaction can be:
 - excitation of the atom with energy loss E = E1 E2
 - ionization with energy loss distribution $g(E) \sim 1/E2$
- PAI model uses photo absorption data
- All energy transfers are sampled with production of secondary electrons and photons
 - Slow model, should only be applied for sensitive region



Low Energy Electromagnetic Physics

Overview

What is

- A package in the Geant4 electromagnetic package
 - geant4/source/processes/electromagnetic/lowenergy/
- A set of processes extending the coverage of electromagnetic interactions in Geant4 down to "low" energy
 - 250 eV (in principle even below this limit)/100 ev for electrons and photons
 - down to the approximately the ionisation potential of the interacting material for hadrons and ions
- A set of processes based on detailed models
 - shell structure of the atom
 - precise angular distributions
- Complementary to the "standard" electromagnetic package



Overview of physics

- Compton scattering
- Rayleigh scattering
- Photoelectric effect
- Pair production
- Bremsstrahlung
- Ionisation
- Polarised Compton
- + atomic relaxation
 - fluorescence
 - Auger effect

following processes leaving a vacancy in an atom

in two "flavours" of models:

- based on the Livermore Library
- à la Penelope

+ models for hadrons/ions



LowE processes based on Livermore Library



Photons and electrons

different approach w.r.t. Geant4 standard e.m. package

- Based on evaluated data libraries from LLNL:
 - EADL (Evaluated Atomic Data Library)
 - EEDL (Evaluated Electrons Data Library)
 - EPDL97 (Evaluated Photons Data Library)

especially formatted for Geant4 distribution (courtesy of D. Cullen, LLNL)

- Validity range: 250 eV 100 GeV
 - The processes can be used down to 100 eV, with degraded accuracy
 - In principle the validity range of the data libraries extends down to ∼10 eV
- Elements Z=1 to Z=100
 - Atomic relaxation: Z > 5 (transition data available in EADL)

Calculation of cross sections

Interpolation from the data libraries:

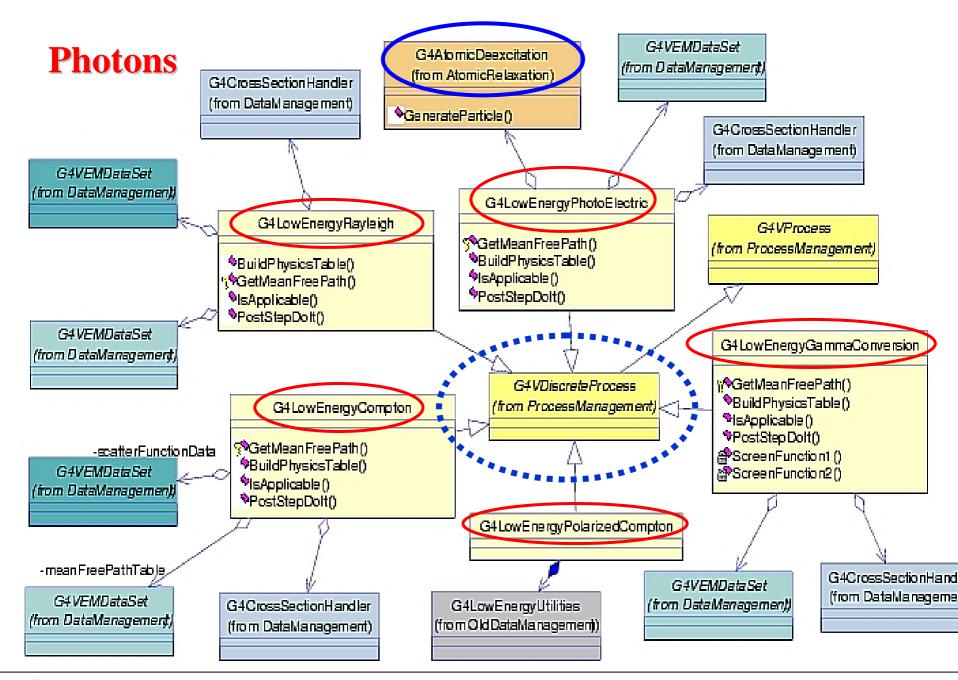
$$\log(\sigma(E)) = \frac{\log(\sigma_1)\log(E_2/E) + \log(\sigma_2)\log(E/E_1)}{\log(E_2/E_1)}$$

 E_1 and E_2 are the lower and higher energy for which data (σ_1 and σ_2) are available

Mean free path for a process, at energy E:

$$\lambda = \frac{1}{\sum_{i} \sigma_{i}(E) \cdot n_{i}}$$

 n_i = atomic density of the i^{th} element contributing to the material composition



Compton scattering

Klein-Nishina cross section:
$$\frac{d\sigma}{d\Omega} = \frac{1}{4} r_0^2 \frac{h v^2}{h v_0^2} \left[\frac{h v_0}{h v} + \frac{h v}{h v_0} - 2 + 4\cos^2\Theta \right]$$

- Energy distribution of the scattered photon according to the Klein-Nishina formula, multiplied by scattering function F(q) from EPDL97 data library
- The effect of scattering function becomes significant at <u>low energies</u>
 - suppresses forward scattering
- Angular distribution of the scattered photon and the recoil electron also based on EPDL97

Rayleigh scattering

- Angular distribution: F(E,q)=[1+cos²(q)]·F²(q)
 - where F(q) is the energy-dependent form factor obtained from EPDL97
- This process is only available in the *lowenergy* package
 - Not available in the standard package

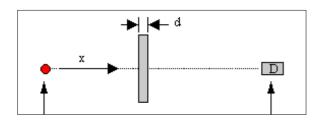
Photoelectric effect

- Cross section
 - Integrated cross section (over the shells) from EPDL + interpolation
 - Shell from which the electron is emitted selected according to the detailed cross sections of the EPDL library
- Final state generation
 - Various angular distribution generators ("naïve", Sauter-Gavrila, Gavrila)
- Deexcitation via the atomic relaxation sub-process
 - Initial vacancy + following chain of vacancies created
- Improved angular distribution in preparation

γ conversion

- The secondary e⁻ and e⁺ energies are sampled using Bethe-Heitler cross sections with Coulomb correction
- e- and e+ assumed to have symmetric angular distribution
- Energy and polar angle sampled w.r.t. the incoming photon using Tsai differential cross section
- Azimuthal angle generated isotropically
- Choice of which particle in the pair is e⁻ or e⁺ is made randomly

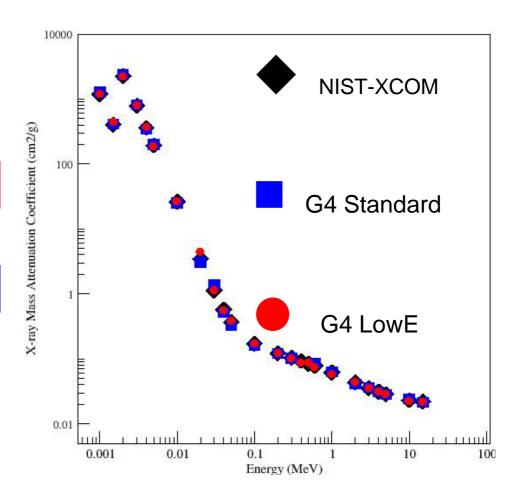
Photons: mass attenuation coefficient



$$\chi^2_{N-L}$$
=13.1 – ν =20 - p=0.87

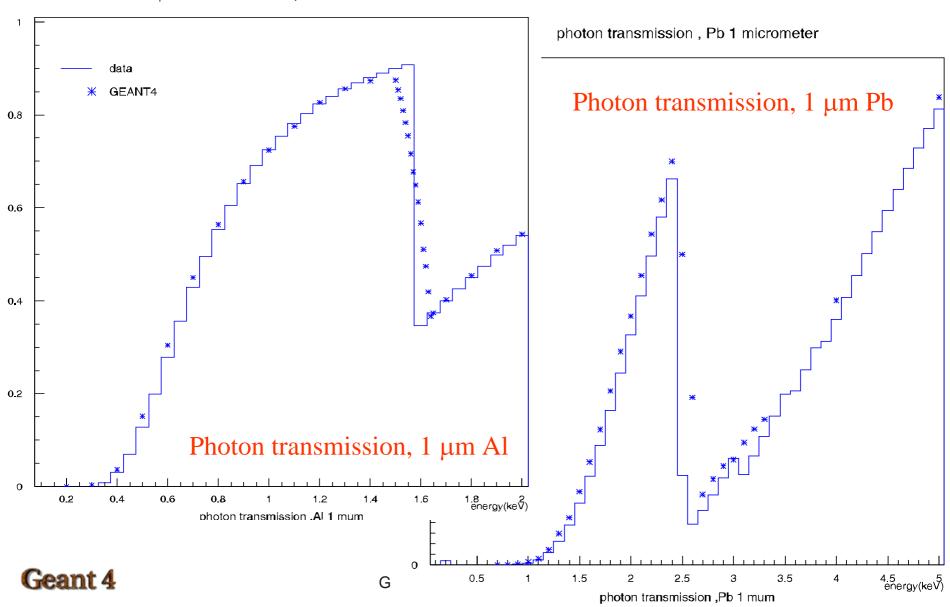
$$\chi^2_{N-S} = 23.2 - \nu = 15 - p = 0.08$$

Comparison against NIST data



Photons, evidence of shell effects

photon transmission, Al 1 micrometer



Polarisation

Cross section:
$$\frac{d\sigma}{d\Omega} = \frac{1}{2} r_0^2 \frac{h v^2}{h v_0^2} \left[\frac{h v_0}{h v} + \frac{h v}{h v_0} - 2 \sin^2 \theta \cos^2 \phi \right]$$

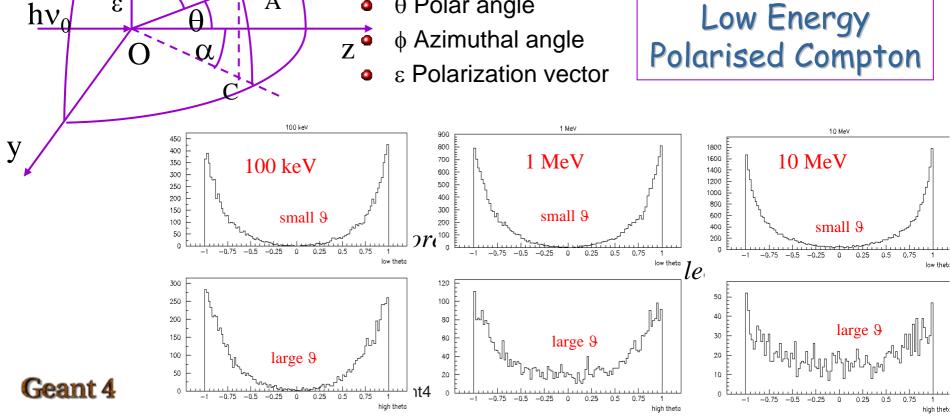
$$cos\xi = sin\theta cos\phi \implies sin\xi = \sqrt{1 - sin^2\theta cos^2\phi} = N$$

$$Scattered \ Photon \ Polarization \ \vec{\epsilon_\perp} = \frac{1}{N} \left(cos\theta \ \hat{j} - sin\theta sin\phi \ \hat{k} \right) sin\beta$$

$$\vec{\epsilon_\parallel} = \left(N\hat{i} - \frac{1}{N} sin^2\theta sin\phi cos\phi \ \hat{j} - \frac{1}{N} sin\theta cos\theta cos\phi \ \hat{k} \right) cos\beta$$

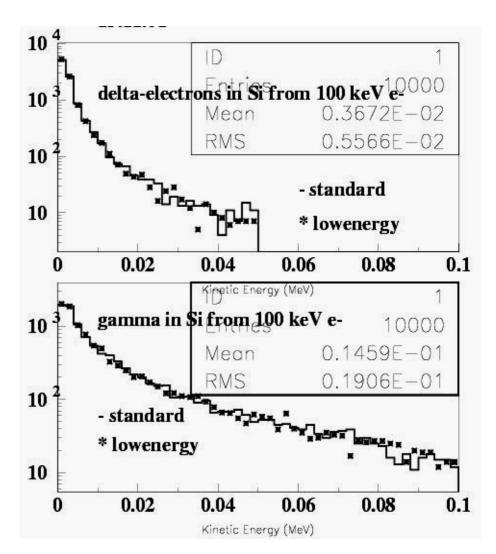
θ Polar angle

Low Energy



Electron Bremsstrahlung

- Parameterisation of EEDL data
 - 16 parameters for each atom
 - At high energy the parameterisation reproduces the Bethe-Heitler formula
 - Precision is ~ 1.5 %

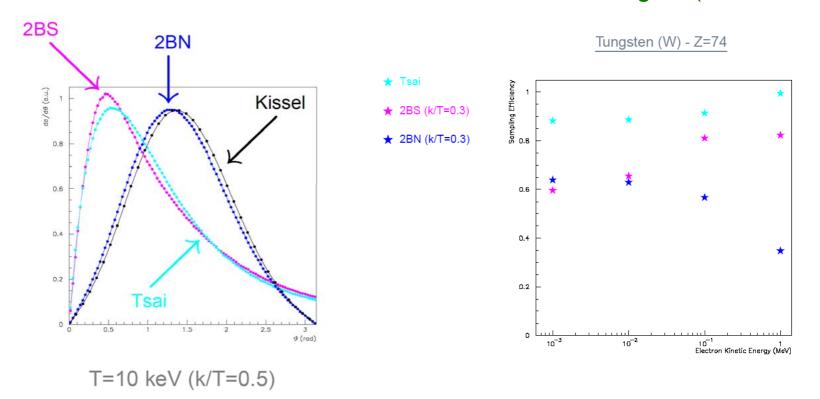




Bremsstrahlung Angular Distributions

Three LowE generators available in GEANT4 6.0 release:

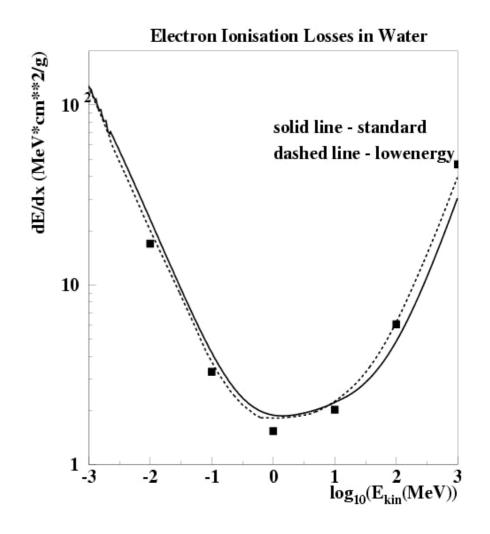
G4ModifiedTsai, G4Generator2BS and G4Generator2BN G4Generator2BN allows a correct treatment at low energies (< 500 keV)





Electron ionisation

- Parameterisation based on 5 parameters for each shell
- Precision of parametrisation is better then 5% for 50 % of shells, less accurate for the remaining shells



Electrons: range

Range in various simple and composite materials

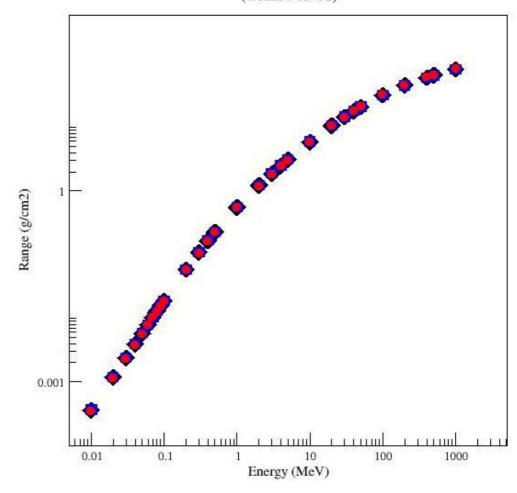
Compared to NIST database



G4 Standard

G4 LowE

Electrons - CSDA Range - Aluminium (Geant4-05-02)



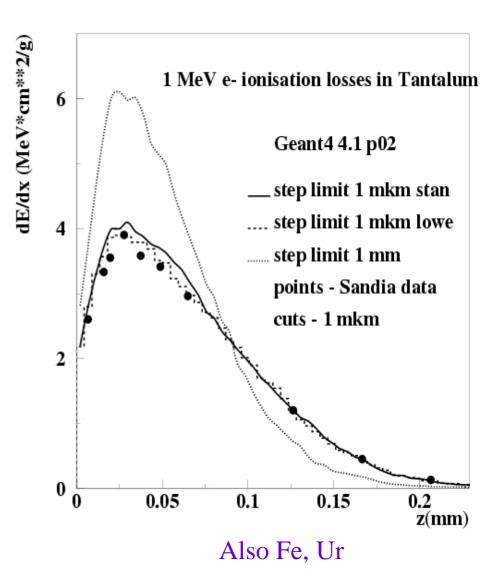


Electrons: dE/dx

Ionisation energy loss in various materials

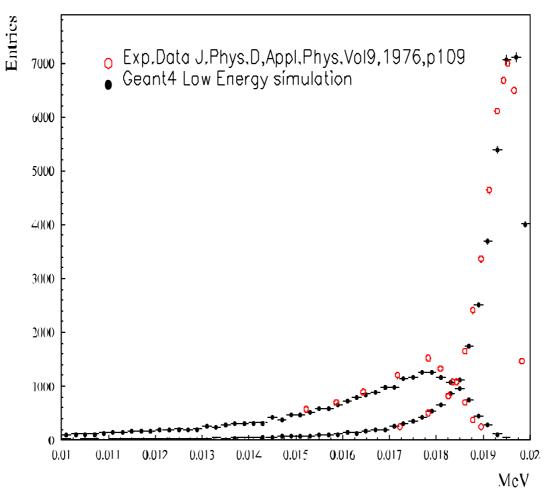
Compared to Sandia database

More systematic verification planned



Electrons, transmitted

20 keV electrons, 0.32 and 1.04 μm Al



Geant4 validation vs. NIST database

- All Geant4 physics models of electrons, photons, protons and α compared to NIST database
 - Photoelectric, Compton, Rayleigh, Pair Production cross-sections
 - Photon attenuation coefficients
 - Electron, proton, α stopping power and range
- Quantitative comparison
 - Statistical goodness-of-fit tests
- Other validation projects in progress



NIST Test

- Photon Mass Attenuation Coefficient
- Photon Partial Interaction Coefficient
 - related to the Cross section of a specific photon interaction process
- Electron CSDA range and Stopping Power
- Proton CSDA range and Stopping Power
- α CSDA range and Stopping Power

Elements

Be, Al, Si, Fe, Ge, Ag, Cs, Au, Pb, U (span the periodic element table)

Energy range

photon 1 keV - 100 GeV electron 10 keV - 1 GeV proton 1 keV - 10 GeV α 1 keV - 1 GeV

Simulation configuration reproducing NIST conditions (ionisation potential, fluctuations, production of secondaries etc.)

Geant4 models: electrons and photons
Standard
Low Energy EEDL/EPDL
Low Energy Penelope

Geant4 models: protons and α

Standard

Low Energy ICRU49

Low Energy Ziegler 1977

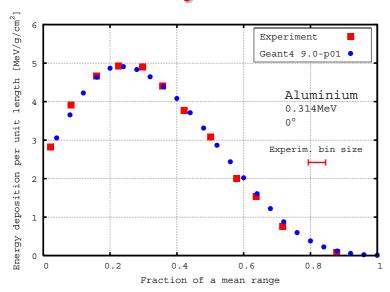
Low Energy Ziegler 1985

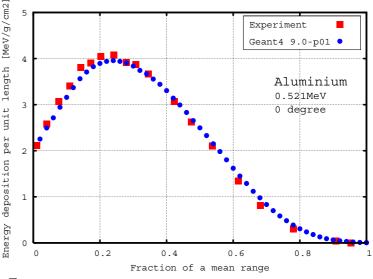
Low Energy Ziegler 2000

(Low Energy: free electron gas + parameterisations + Bethe-Bloch)



Dosimetry with Geant4 LowE EM package

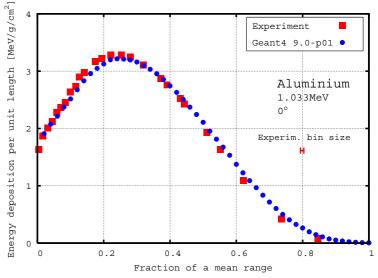




Energy deposit in calorimeter

Experimental data

G.J. Lockwood et al.,
"Calorimetric Measurement of Electron
Energy Deposition in Extented
Media - Theory vs. Experiment",
SAND79-0414 UC-34a, 1987.



A. Lechner, M.G. Pia, M. Sudhakar IEEE NSS 2007 Confe Recoulte E to Na Best Student Paper Award

Effect of secondary production threshold

Geant4 Low Energy Electromagnetic

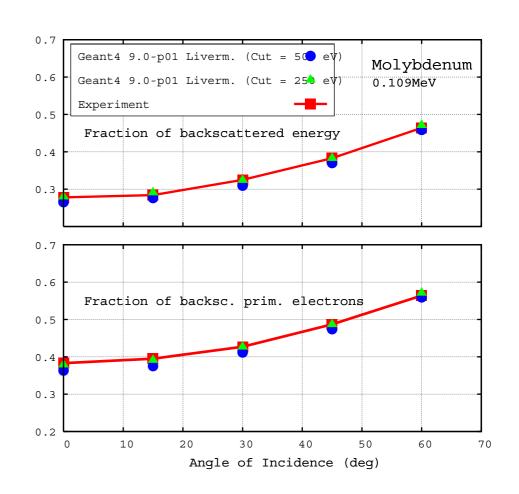
250 eV

EGS

Geant4 Standard Electromagnetic

MCNP

1 keV



Example 5.2. Registration of electromagnetic low energy electron/photon processes.

```
void LowEnPhysicsList::ConstructEM()
  theParticleIterator->reset();
  while( (*theParticleIterator)() ) {
    G4ParticleDefinition* particle = theParticleIterator->value();
    G4ProcessManager* pmanager = particle->GetProcessManager();
    G4String particleName = particle->GetParticleName();
    if (particleName == "gamma") {
                           = new G4LowEnergyPhotoElectric();
      theLEPhotoElectric
                           = new G4LowEnergyCompton();
      theLECompton
      theLEGammaConversion = new G4LowEnergyGammaConversion();
      theLERayleigh
                          = new G4LowEnergyRayleigh();
      pmanager->AddDiscreteProcess(theLEPhotoElectric);
      pmanager->AddDiscreteProcess(theLECompton);
      pmanager->AddDiscreteProcess(theLERayleigh);
      pmanager->AddDiscreteProcess(theLEGammaConversion);
    else if (particleName == "e-") {
      theLEIonisation = new G4LowEnergyIonisation();
      theLEBremsstrahlung = new G4LowEnergyBremsstrahlung();
      theeminusMultipleScattering = new G4MultipleScattering();
      pmanager->AddProcess(theeminusMultipleScattering,-1,1,1);
      pmanager->AddProcess(theLEIonisation,-1,2,2);
      pmanager->AddProcess(theLEBremsstrahlung,-1,-1,3);
    }
```

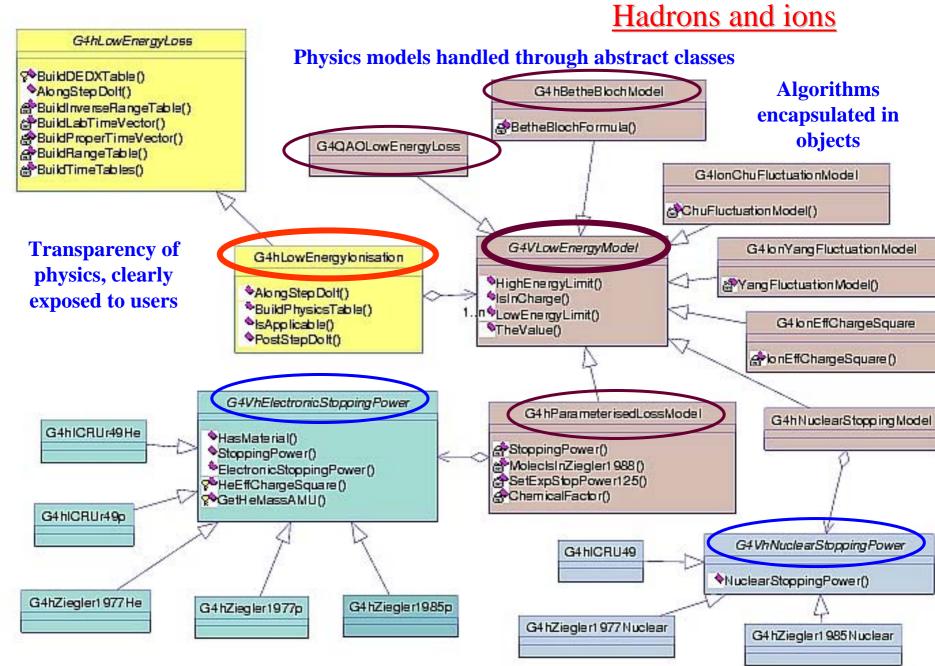
Processes à la Penelope

- The whole physics content of the Penelope Monte Carlo code has been re-engineered into Geant4 (except for multiple scattering)
 - processes for photons: release 5.2, for electrons: release 6.0
- Physics models by F. Salvat et al.
- Power of the OO technology:
 - extending the software system is easy
 - all processes obey to the same abstract interfaces
 - using new implementations in application code is simple
- Profit of Geant4 advanced geometry modeling, interactive facilities etc.
 - same physics as original Penelope



Hadrons and ions

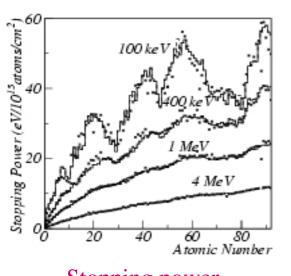
- Variety of models, depending on
 - energy range
 - particle type
 - charge
- Composition of models across the energy range, with different approaches
 - analytical
 - based on data reviews + parameterisations
- Specialised models for fluctuations
- Open to extension and evolution



Interchangeable and transparent access to data sets

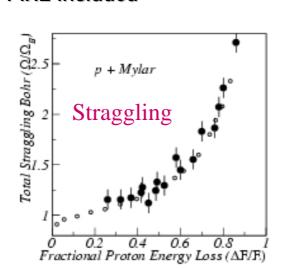
Positive charged hadrons

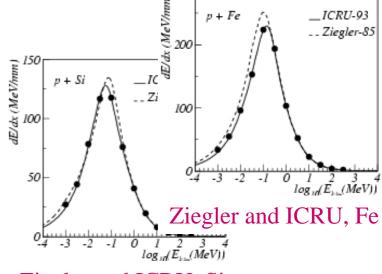
- Bethe-Bloch model of energy loss, E > 2 MeV
- 5 parameterisation models, E < 2 MeV
 - based on Ziegler and ICRU reviews
- 3 models of energy loss fluctuations
- Density correction for high energy
- Shell correction term for intermediate energy



Stopping power
Z dependence for various energies
Ziegler and ICRU models

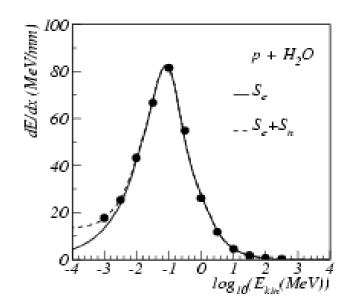
- -Chemical effect for compounds
- Nuclear stopping power
- PIXE included





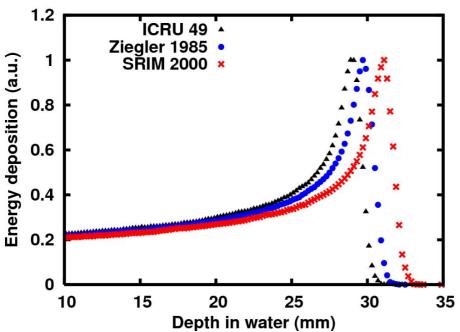
Ziegler and ICRU, Si

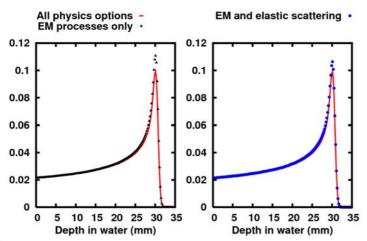
- -Spin dependent term
- Barkas and Bloch terms

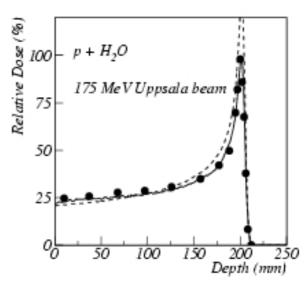


Nuclear stopping power

Further activity in progress







Bragg peak

(with hadronic interactions)



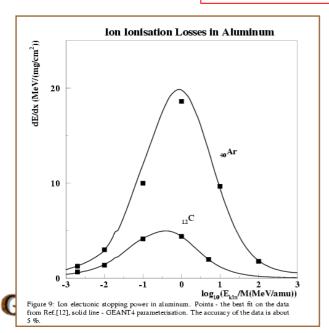
Geant4 Course - M. G. Pia

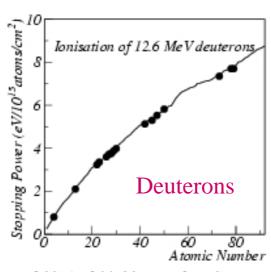
Positive charged ions

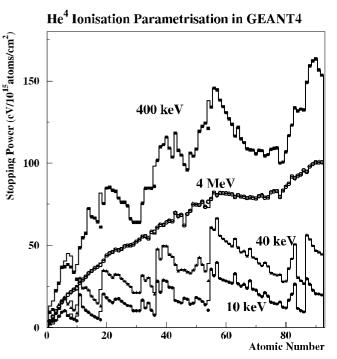
• Scaling:

$$S_{ion}(T) = Z_{ion}^2 S_p(T_p), T_p = T \frac{m_p}{m_{ion}}$$

- $0.01 < \beta < 0.05$ parameterisations, Bragg peak
 - based on Ziegler and ICRU reviews
- β < 0.01: Free Electron Gas Model
 - Effective charge model
 - Nuclear stopping power







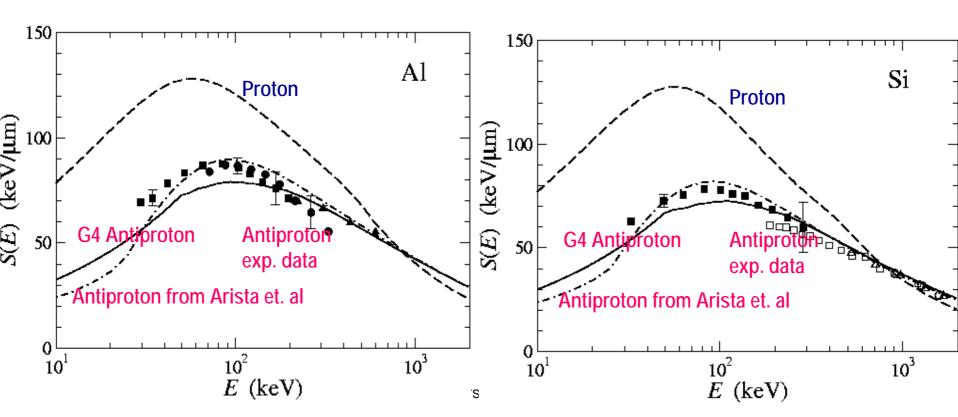
Models for antiprotons

- $\beta > 0.5$
- $0.01 < \beta < 0.5$
- β < 0.01

Bethe-Bloch formula

Quantum harmonic oscillator model

Free electron gas mode



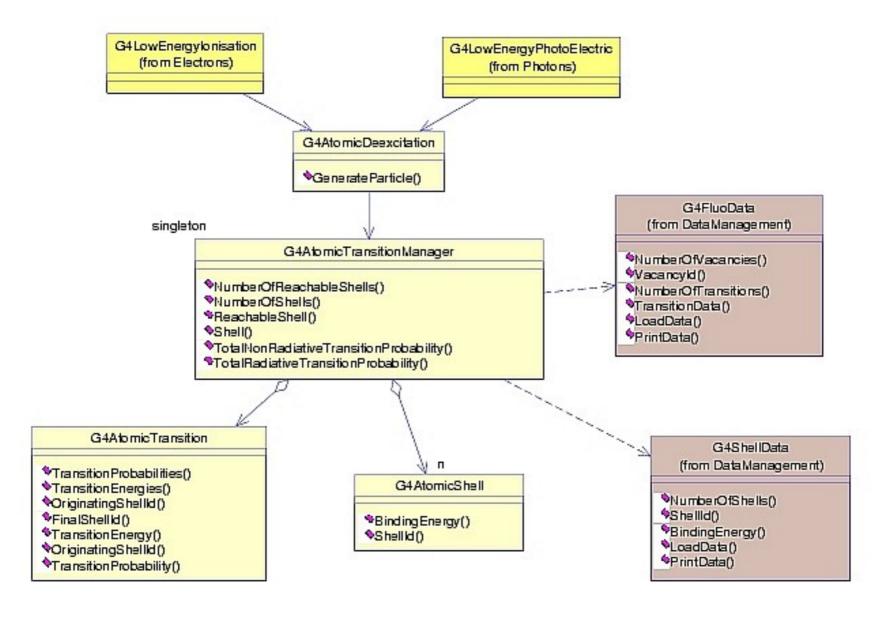
Options for G4hLowEnergyIonisation

G4hLowEnergyIonisation* hIonisation = new G4hLowEnergyIonisation; hIonisation->Set...();

- •SetHighEnergyForProtonParametrisation(G4double)
- SetLowEnergyForProtonParametrisation(G4double)
- SetHighEnergyForAntiProtonParametrisation(G4double)
- SetLowEnergyForAntiProtonParametrisation(G4double)
- **SetElectronicStoppingPowerModel**(const G4ParticleDefinition*,const G4String&)
- **SetNuclearStoppingPowerModel**(const G4String&)
- SetNuclearStoppingOn()
- SetNuclearStoppingOff()
- SetBarkasOn()
- SetBarkasOff()
- SetFluorescence(const G4bool)
- ActivateAugerElectronProduction(G4bool)
- SetCutForSecondaryPhotons(G4double)
- SetCutForSecondaryElectrons(G4double)

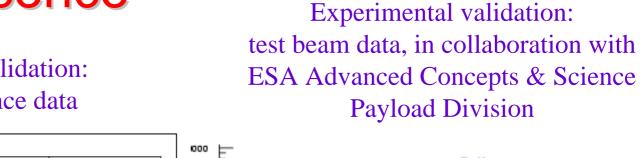


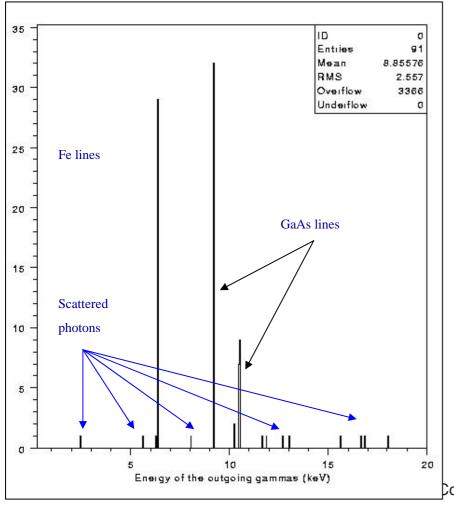
Atomic relaxation

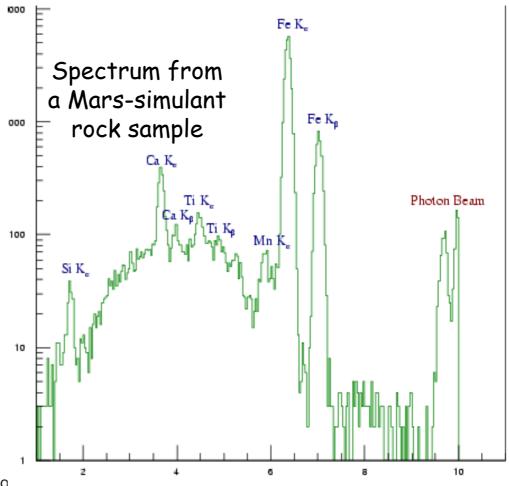


Fluorescence

Microscopic validation: against reference data



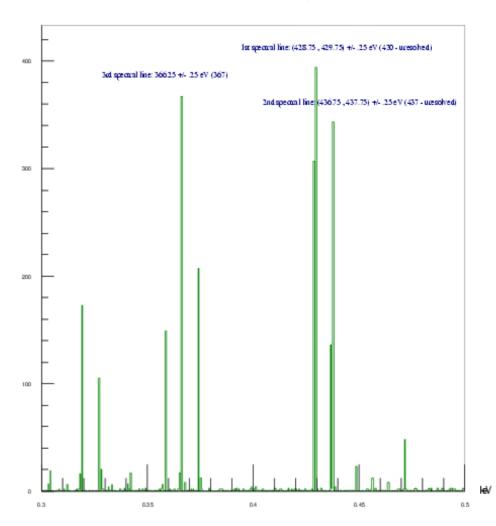




Auger effect

Electron emission from Sn - 3 KeV photon Beam

Sn, 3 keV photon beam, electron lines w.r.t. published experimental results



PIXE

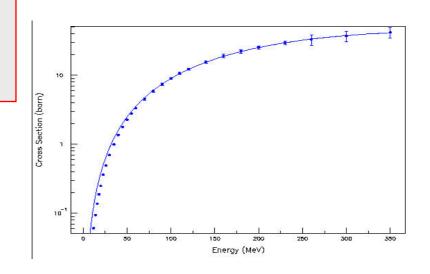
- Model based on experimental data
 - Parameterisation of Paul & Sacher data library for ionisation cross sections
 - Uses the EADL-based package of atomic deexcitation for the generation of fluorescence and Auger secondary products
- Geant4 9.1 implementation: protons, K-shell
- Further developments (and problems)

Talk by G. Weidenspointner NSS session N41-4 on Thursday morning

Example of p ionisation cross section, K shell

parameterisation (solid line)

Experimental data





Further documentation on Geant4 Atomic Relaxation

IEEE TRANSACTIONS ON NUCLEAR SCIENCE, VOL. 54, NO. 3, JUNE 2007

38.5

Geant4 Atomic Relaxation

2007

Susanna Guatelli, Alfonso Mantero, Barbara Mascialino, Petteri Nieminen, and Maria Grazia Pia

594

IEEE TRANSACTIONS ON NUCLEAR SCIENCE, VOL. 54, NO. 3, JUNE 2007

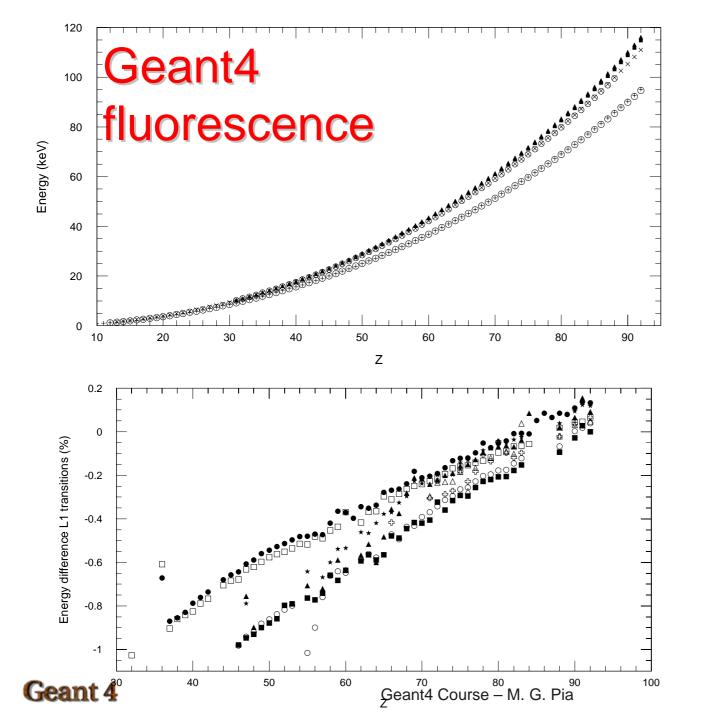
Validation of Geant4 Atomic Relaxation Against the NIST Physical Reference Data

S. Guatelli, A. Mantero, B. Mascialino, M. G. Pia, and V. Zampichelli

2007

More in preparation (M.G. Pia et al.)

2008

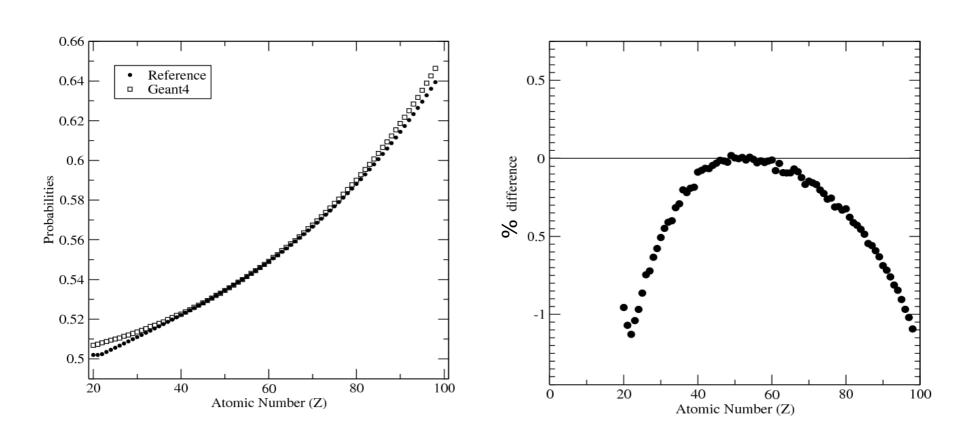


Transition	p-value
KL_2	1
KL_2	1
\widetilde{KM}_2	1
KM_4	1
KM _c	1
KN ₂	1
KN_2^2	1
L_1M_2	1
$L_1^1 M_2^2$	1
$L_1^{\dagger}M_A^{3}$	1
$L_1^{\dagger}M_5^{\dagger}$	1
$L_1^1 N_2^3$	1
$L_1^1 N_2^2$	1
$L_1^1 N_4^3$	0.997
$L_1^1 N_{\epsilon}^4$	1
$L_2^{1}M_1^{2}$	1
$L_2^2 M_2^2$	1
$L_2^2 M_4^3$	1
L_2N_2 or L_2N_3	1
L_2N_2	1
$L_2^2 N_4^3$	1
$L_2^2 N_c^4$	1
$L_2^2 M_1^0$	1
$L_2^3 M_2^1$	1
$L_2^3 M_2^2$	1
L_2M_4	1
$L_2^3M_5^4$	1
L_2N_2 or L_2N_2	1
L_2N_2	1
L_2N_2	1
L_2N_4	1
L_2N_5	1

Goodness of fit test

Goodness-of-fit test	p-
Anderson-Darling	1 ^{val}
Cramer-von Mises	1
Kolmogorov-Smirnov	1
Kuiper	1
Watson	1

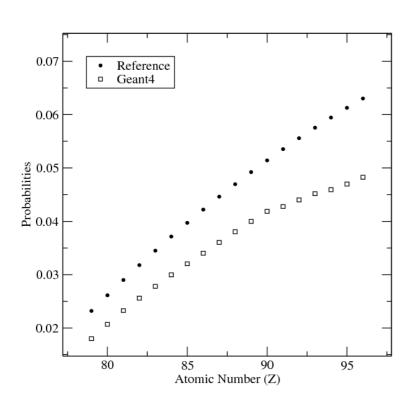
Fluorescence transition probabilities

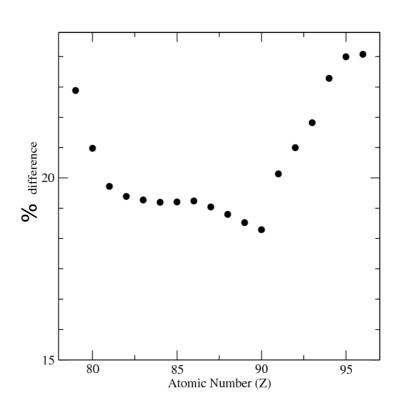


Experimental reference:

W.T. Elam, B.D. Ravel, J.R. Sieber, *A new atomic database for X-ray spectroscopic calculations,* Radiat. Phys. Chem. 63 (2002) 121–128

Bad but harmless...

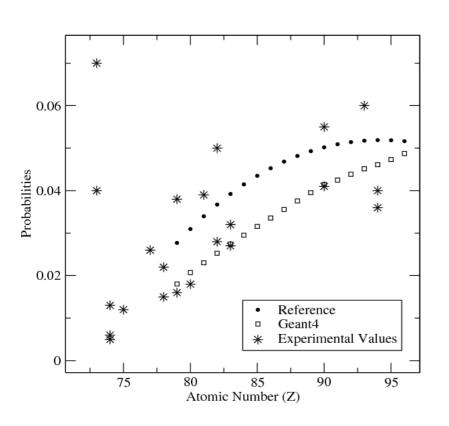


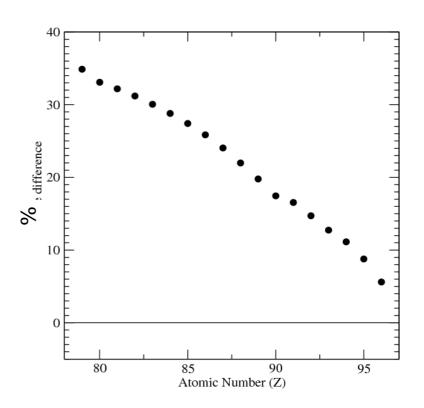


25% absolute error \Rightarrow 0.04% error in an experimental use case



Hard to say...

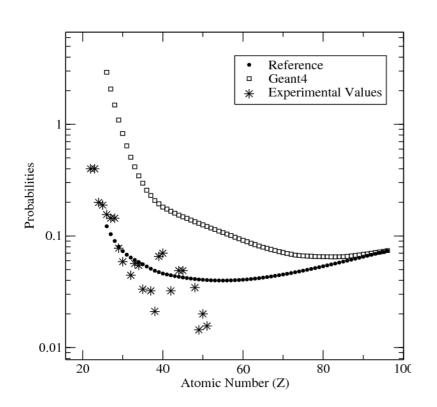


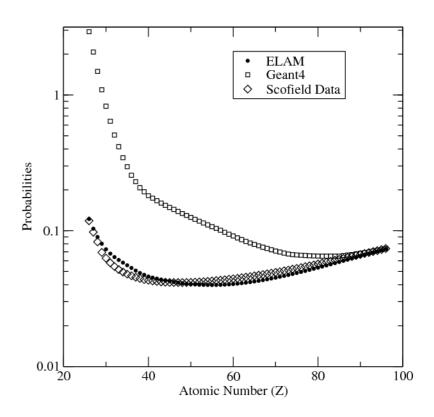


Controversial experimental data



Hidden for 17 years...





The error is in EADL!

In progress

Extensions down to the eV scale

- In water (for radiobiology studies)
- Other materials (gas, solids)

Difficult domain

- Models must be specialised by material
- Cross sections, final state generation, angular distributions

1st development cycle: Very-low energy extensions

Physics of interactions in water down to the eV scale

Complex domain

- Physics: collaboration with theorists
- Technology: innovative design technique introduced in Geant4
 (1st time in Monte Carlo)

Experimental complexity as well

- Scarce experimental data
- Collaboration with experimentalists for model validation
- Geant4 physics validation at low energies is difficult!

S. Chauvie et al., Geant4 physics processes for microdosimetry simulation: design foundation and implementation of the first set of models, IEEE Trans. Nucl. Sci., Vol. 54, no. 6, pp. 2619-2628, Dec. 2007

Geant4-DNA physics processes

Specialised processes for low energy interactions with water

Models in liquid water

- More realistic than water vapour
- Theoretically more challenging
- Hardly any experimental data
- New measurements needed

Status

- 1st β-release Geant4 8.1 2006
- Full release December 2007
- Further extensions in progress

Current focus

Experimental comparisons

Toolkit: offer a wide choice among available alternative models for each process

Particle	Processes
e ⁻	Elastic scattering Excitation Ionisation
р	Charge decrease Excitation Ionisation
Н	Charge increase Ionisation
He++	Charge decrease Excitation Ionisation
He+	Charge decrease Charge increase Excitation Ionisation
He	Charge increase Excitation Ionisation

Geant 4

Geant4 Course - M. G. Pia

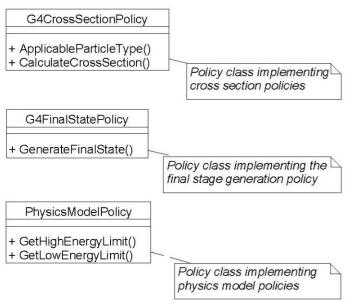
What is behind...

Policy-based class design

- A policy defines a class or class template interface
- Policy host classes are parameterised classes
 - classes that use other classes as a parameter
- Advantage w.r.t. a conventional strategy pattern
 - Policies are not required to inherit from a base class
 - The code is bound at compilation time
 - No need of virtual methods, resulting in faster execution

New technique

1st time introduced in Monte Carlo



Weak dependency of the policy and the policy based class on the policy interface

Highly **customizable** design Open to extension

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Geant4-DNA physics process

Handled transparently by Geant4 kernel

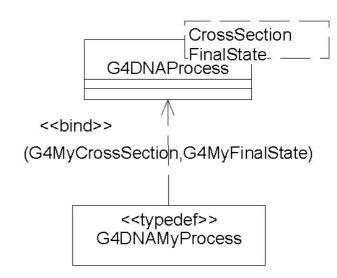
G4VProcess

(from processes management) + AlongStepDolt() + AlongStepGetPhysicalInteractionLength() + AtRestDolt() + AtRestGetPhysicalInteractionLength() + PostStepDolt() + PostStepGetPhysicalInteractionLength() + IsApplicable() G4VDiscreteProcess (from processes management) # GetMeanFreePath() + PostStepDolt() CrossSection FinalState G4DNAProcess

GetMeanFreePath()

+ IsApplicable() + PostStepDoIt() Deprived of any intrinsic physics functionality

Configured by template specialization to acquire physics properties





From **cells** to **plasma**...

Proton charge transfer processes for 12 materials

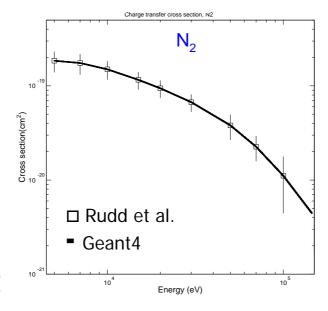
(He, water vapour, N₂, CO, CO₂, hydrocarbons)

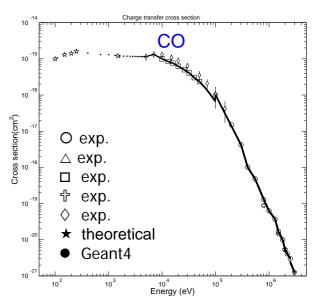
Relevant to astrophysics and fusion reactor design

Development metrics

in Easter egg

Design investment pays back!





M.E. Rudd et al., Phys. Rev. A 28, 3244-3257, 1983 L.H. Toburen et al., Phys. Rev 171,114 - 122, 1968 S.L. Varghese et al., Phys. Rev. A31, 2202-2209, 1985 M.B. Shah and H.B. Gilbody, J. Phys. B 23, 1491-1499, 1990 R.S. Gao et al., Phys. Rev. A 41, 5929-5933, 1990 M. Kimura et al., Phys. Rev. A 61, 032708, 2000

How to use policy-based processes

// Definition

```
typedef G4DNAProcess<G4CrossSectionElasticScreenedRutherford,G4FinalStateElasticScreenedRutherford> ElasticScreenedRutherford; typedef G4DNAProcess<G4CrossSectionExcitationEmfietzoglou,G4FinalStateElasticBrennerZaider> ElasticBrennerZaider; typedef G4DNAProcess<G4CrossSectionExcitationEmfietzoglou,G4FinalStateExcitationEmfietzoglou> ExcitationEmfietzoglou; typedef G4DNAProcess<G4CrossSectionExcitationBorn,G4FinalStateExcitationBorn> ExcitationBorn; typedef G4DNAProcess<G4CrossSectionIonisationBorn,G4FinalStateIonisationBorn> IonisationBorn; typedef G4DNAProcess<G4CrossSectionIonisationRudd,G4FinalStateIonisationRudd> IonisationRudd; typedef G4DNAProcess<G4CrossSectionExcitationMillerGreen,G4FinalStateExcitationMillerGreen> ExcitationMillerGreen; typedef G4DNAProcess<G4CrossSectionChargeDecrease,G4FinalStateChargeDecrease> ChargeDecrease; typedef G4DNAProcess<G4CrossSectionChargeIncrease,G4FinalStateChargeIncrease> ChargeIncrease;
```

// Registration

```
if (particleName == "e-")
{
    processManager->AddDiscreteProcess(new ExcitationEmfietzoglou);
    processManager->AddDiscreteProcess(new ElasticScreenedRutherford);
    processManager->AddDiscreteProcess(new ElasticBrennerZaider);
    processManager->AddDiscreteProcess(new IonisationBorn);
}
```

Physics models and their validation

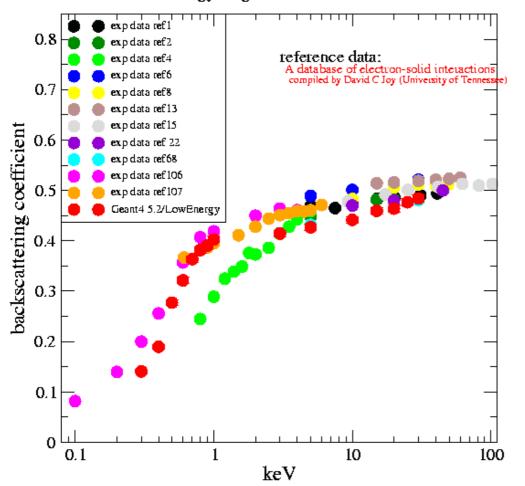
- S. Chauvie et al.,
 Geant4 physics processes for microdosimetry simulation: design foundation and implementation of the first set of models IEEE Trans. Nucl. Sci., vol. 54, no. 6, Dec. 2007
- S. Chauvie, P. Nieminen, M. G. Pia
 Geant4 model for the stopping power of low energy negatively charged hadrons
 - IEEE Trans. Nucl. Sci., vol. 54, no. 3, pp. 578-584, Jun. 2007
- S. Guatelli, A. Mantero, B. Mascialino, P. Nieminen, M. G. Pia Geant4 Atomic Relaxation
 IEEE Trans. Nucl. Sci., vol. 54, no. 3, pp. 585-593, Jun. 2007
- S. Guatelli, A. Mantero, B. Mascialino, P. Nieminen, M. G. Pia, V. Zampichelli
 Validation of Geant4 Atomic Relaxation against the NIST Physical
 Reference Data
 - IEEE Trans. Nucl. Sci., vol. 54, no. 3, Jun. 2007, pp. 594-603
- K. Amako et al.,
 Comparison of Geant4 electromagnetic physics models against the NIST reference data
- Geant 4 Trans. Nucl. Sci., vol. 52, no. 4, pp. 910-918, Aug. 2005

 Geant 4 Course M. G. Pia

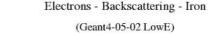
The problem of validation: finding reliable data

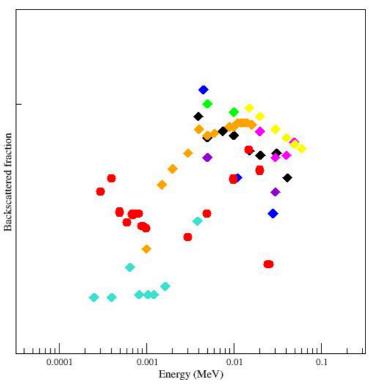
backscattering for e-

e- energy range: 0.1 keV -> 102. keV



Backscattering low energies - Au





Note: Geant4 validation is not always easy

gies - Au experimental data often experimental data often experimental data often exhibit large differences!

Geant 4

Summary

- OO technology provides the mechanism for a rich set of electromagnetic physics models in Geant4
 - further extensions and refinements are possible, without affecting
 Geant4 kernel or user code
- Two main approaches in Geant4:
 - Standard package
 - Low Energy package
 - each one offering a variety of models for specialised applications
- Extensive validation activity and results
- More on Physics Reference Manual and web site

